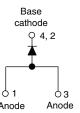
Vishay Semiconductors

FREE

High Performance Schottky Rectifier, 3.5 A





D-PAK (TO-252AA)

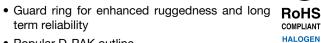
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PRODUCT SUMMARY	
Package	D-PAK (TO-252AA)
I _{F(AV)}	3.5 A
V _R	30 V
V _F at I _F	See Electrical table
I _{RM}	50 mA at 125 °C
T _J max.	150 °C
Diode variation	Single die
E _{AS}	8 mJ

FEATURES

Low forward voltage drop



- Popular D-PAK outline
- · Small foot print, surface mountable
- High frequency operation
- · Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION

The VS-30WQ03FN-M3 surface mount Schottky rectifier has been designed for applications requiring low forward drop and small foot prints on PC board. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS									
SYMBOL	CHARACTERISTICS	VALUES	UNITS						
I _{F(AV)}	Rectangular waveform	3.5	А						
V _{RRM}		30	V						
I _{FSM}	t _p = 5 μs sine	535	A						
V _F	3 A _{pk} , T _J = 125 °C	0.35	V						
TJ	Range	-40 to +150	°C						

VOLTAGE RATINGS								
PARAMETER	SYMBOL	VS-30WQ03FN-M3	UNITS					
Maximum DC reverse voltage	V _R	30	M					
Maximum working peak reverse voltage	V _{RWM}	50	v					

ABSOLUTE MAXIMUM RATINGS								
PARAMETER	SYMBOL	TEST COND	VALUES	UNITS				
Maximum average forward current See fig. 5	I _{F(AV)}	50 % duty cycle at T _C = 134 °C	3.5					
Maximum peak one cycle non-repetitive surge current	1	5 µs sine or 3 µs rect. pulse	Following any rated load condition and with rated	535	А			
See fig. 7	IFSM	10 ms sine or 6 ms rect. pulse	V _{RRM} applied	90				
Non-repetitive avalanche energy	E _{AS}	T _J = 25 °C, I _{AS} = 2 A, L = 4 mH		8	mJ			
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero Frequency limited by T_J maximum	1.0	А				

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ELECTRICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CONE	DITIONS	VALUES	UNITS			
		3 A	T,I = 25 °C	0.45	V			
Maximum forward voltage drop See fig. 1	V _{EM} ⁽¹⁾	6 A	1j=25 0	0.52				
	VFM ("	3 A	T 105 %O	0.35				
		6 A	T _J = 125 °C	0.46				
Maximum reverse leakage current	I _{RM} ⁽¹⁾	T _J = 25 °C	$V_{\rm B}$ = Rated $V_{\rm B}$	2	mA			
See fig. 2	IRM \''	T _J = 125 °C	VR = naleu VR	50				
Threshold voltage	V _{F(TO)}	T T maximum		0.22	V			
Forward slope resistance	r _t	ij = ij maximum	$T_J = T_J maximum$		mΩ			
Typical junction capacitance	CT	$V_R = 5 V_{DC}$ (test signal range	290	pF				
Typical series inductance	L _S	Measured lead to lead 5 mm	5.0	nH				
Maximum voltage rate of change	dV/dt	Rated V _R		10 000	V/µs			

Note

 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS									
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS					
Maximum junction and storage temperature range	T _J ⁽¹⁾ , T _{Stg}		-40 to +150	°C					
Maximum thermal resistance, junction to case	R _{thJC}	DC operation See fig. 4	4.7	°C/W					
Approximate weight			0.3	g					
Approximate weight			0.01	oz.					
Marking device		Case style D-PAK (similar to TO-252AA)	30WC	03FN					

Note

(1) $\frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}}$ thermal runaway condition for a diode on its own heatsink

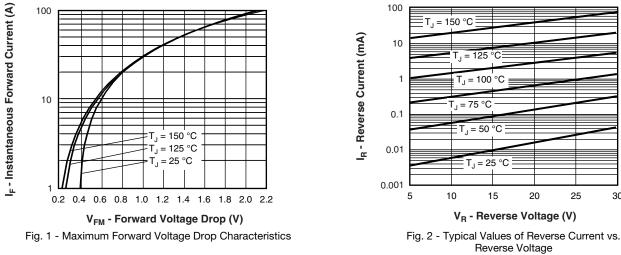
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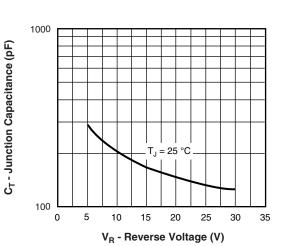


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

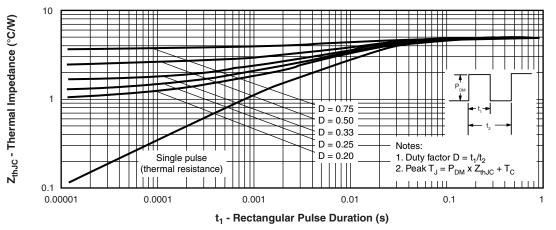
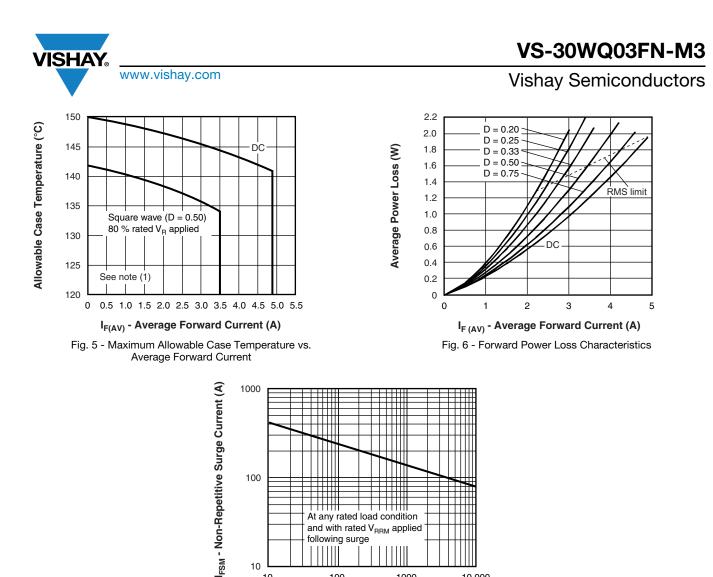


Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics



Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$; $Pd = forward power loss = I_{F(AV)} \times V_{FM} at (I_{F(AV)}/D)$ (see fig. 6); $Pd_{REV} = inverse power loss = V_{R1} \times I_R (1 - D)$; $I_R at V_{R1} = 80 \%$ rated V_R

100

10 10 +++++

following surge

100

At any rated load condition and with rated $\mathrm{V}_{\mathrm{RRM}}$ applied

 $t_{\rm p}$ - Square Wave Pulse Duration (µs) Fig. 7 - Maximum Non-Repetitive Surge Current

1000

10 000

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ORDERING INFORMATION TABLE

Device code	vs-	30	w	Q	03	FN	TRL	-M3		
	1	2	3	4	5	6	7	8		
	<u>۱</u> .	- Visl	hay Sem	niconduc	ctors pro	oduct				
	2 - Current rating (3.5 A)									
	3 - Package identifier:									
	W = D-PAK									
	4 -	- Sch	ottky "C	" series						
	5 -	Vol	tage rati	ng (03 =	= 30 V)					
	6	- FN	= TO-25	52AA (D	-PAK)					
	7 -	• N	one = tu	be						
	• TR = tape and reel									
		• TI	 TRL = tape and reel (left oriented) 							
		• TI	RR = tap	be and re	eel (righ	it orient	ed)			
	8 -	- Env	vironmer	ntal digit	:					

-M3 = halogen-free, RoHS-compliant and terminations lead (Pb)-free

ORDERING INFORMATION (Example)								
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION					
VS-30WQ03FN-M3	75	3000	Antistatic plastic tube					
VS-30WQ03FNTR-M3	2000	2000	13" diameter reel					
VS-30WQ03FNTRL-M3	3000	3000	13" diameter reel					
VS-30WQ03FNTRR-M3	3000	3000	13" diameter reel					

LINKS TO RELATED DOCUMENTS						
Dimensions	www.vishay.com/doc?95627					
Part marking information	www.vishay.com/doc?95176					
Packaging information	www.vishay.com/doc?95033					





D-PAK (TO-252AA) "M"

DIMENSIONS in millimeters and inches



SYMBOL	MILLIMETERS		INCHES		NOTES	SYMBOL		MILLIN	IETERS	INC	HES	NOTES
STNIDUL	MIN.	MAX.	MIN.	MAX.	NOTES	NOTES	STIVIDUL	MIN.	MAX.	MIN.	MAX.	NOTES
А	2.18	2.39	0.086	0.094			е	2.29	BSC	0.090	BSC	
A1	-	0.13	-	0.005			Н	9.40	10.41	0.370	0.410	
b	0.64	0.89	0.025	0.035			L	1.40	1.78	0.055	0.070	
b2	0.76	1.14	0.030	0.045			L1	2.74	BSC	0.108	REF.	
b3	4.95	5.46	0.195	0.215	3		L2	0.51	BSC	0.020	BSC	
С	0.46	0.61	0.018	0.024			L3	0.89	1.27	0.035	0.050	3
c2	0.46	0.89	0.018	0.035			L4	-	1.02	-	0.040	
D	5.97	6.22	0.235	0.245	5		L5	1.14	1.52	0.045	0.060	2
D1	5.21	-	0.205	-	3		Ø	0°	10°	0°	10°	
E	6.35	6.73	0.250	0.265	5		Ø1	0°	15°	0°	15°	
E1	4.32	-	0.170	-	3		Ø2	25°	35°	25°	35°	

Notes

⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994

⁽²⁾ Lead dimension uncontrolled in L5

⁽³⁾ Dimension D1, E1, L3 and b3 establish a minimum mounting surface for thermal pad

(4) Section C - C dimension apply to the flat section of the lead between 0.13 and 0.25 mm (0.005 and 0.10") from the lead tip

(5) Dimension D, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body

⁽⁶⁾ Dimension b1 and c1 applied to base metal only

⁽⁷⁾ Datum A and B to be determined at datum plane H

⁽⁸⁾ Outline conforms to JEDEC[®] outline TO-252AA



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